Rev. 2, 1/2005

1800-1900 MHz 4 W, 30 dB **RF LINEAR LDMOS AMPLIFIER**



MHL18336

PCS Band RF Linear LDMOS Amplifier

Designed for ultra-linear amplifier applications in 50 ohm systems operating in the PCS frequency band. A silicon FET Class A design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital modulation systems, such as TDMA and

Replaced by MHL18336N. There are no form, fit or function changes with this part replacement. N suffix added to part number to indicate transition to lead-free

- Third Order Intercept: 46 dBm Typ
- Power Gain: 30 dB Typ (@ f =1850 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- Ideal for Feedforward Base Station Applications

Table 1. Absolute Maximum Ratings (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{DD}	30	Vdc
RF Input Power	P _{in}	+10	dBm
Storage Temperature Range	T _{stg}	- 40 to +100	°C
Operating Case Temperature Range	T _C	- 20 to +100	°C

Table 2. Electrical Characteristics (V_{DD} = 26 Vdc, T_{C} = 25°C; 50 Ω System)

Characteris	tic	Symbol	Min	Тур	Max	Unit
Supply Current		I _{DD}	_	500	525	mA
Power Gain	(f =1850 MHz)	G _p	29	30	31	dB
Gain Flatness	(f = 1800 - 1900 MHz)	G _F	_	0.2	0.4	dB
Power Output @ 1 dB Comp.	(f = 1850 MHz)	P _{out} 1 dB	35	36	_	dBm
Input VSWR	(f = 1800 - 1900 MHz)	VSWR _{in}	_	1.2:1	1.5:1	
Third Order Intercept (f1 = 1847 MHz, f2 = 1852 MHz)		ITO	45	46	_	dBm
Noise Figure	(f = 1850 MHz)	NF	_	4.2	4.5	dB

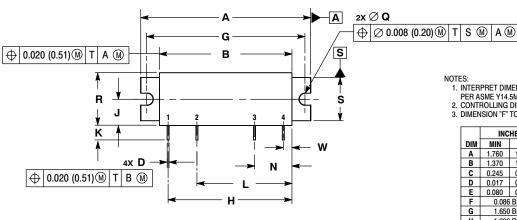


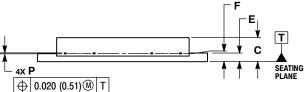
NOTES



ARCHIVE INFORMATION

PACKAGE DIMENSIONS





CASE 301AP-02 ISSUE D

NOTES:

- 1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION "F" TO CENTER OF LEADS.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.760	1.780	44.70	45.21	
В	1.370	1.390	34.80	35.31	
С	0.245	0.265	6.22	6.73	
D	0.017	0.023	0.43	0.58	
Е	0.080	0.100	2.03	2.54	
F	0.086 BSC		2.18 BSC		
G	1.650 BSC		41.91 BSC		
Н	1.290 BSC		32.77 BSC		
J	0.266	0.280	6.76	7.11	
K	0.125	0.165	3.18	4.19	
L	0.990 BSC		25.15 BSC		
N	0.390 BSC		9.91 BSC		
P	0.008	0.013	0.20	0.33	
Q	0.118	0.132	3.00	3.35	
R	0.535	0.555	13.59	14.10	
S	0.445	0.465	11.30	11.81	
W	0.090	BSC	2.29 BSC		

STYLE 1:
PIN 1. RF INPUT
2. VDD1
3. VDD2
4. RF OUTPUT
CASE: GROUND

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